Wideband Microwave Amplifier

AVA-24+

5 to 20 GHz 50Ω

The Big Deal

- Surface Mount Amplifier up to 20 GHz
- Integrated matching, DC Blocks and bias circuits
- High Reverse Isolation



CASE STYLE: DQ849

Product Overview

The Mini-Circuits AVA-24+ is a surface mount, microwave amplifier and fully integrated gain block up to 20 GHz. It is packaged in Mini-Circuits industry standard 3x3 mm MCLP (QFN) package, which provides excellent RF and thermal performance. The AVA-24+ integrates the entire matching network with the majority of the bias circuit inside the package, reducing the need for complicated external circuits. This approach makes the AVA-24+ extremely flexible and enables simple, straightforward use.

Feature	Advantages
Wideband, 5 to 20 GHz	Broad frequency range supports a wide array of applications from microwave radio and radar , to military communications and countermeasures.
Excellent Gain Flatness	Typical ±0.8 dB gain flatness across the entire frequency range minimizes the need for external equalizer networks making it a great fit for instrumentation and EW applications.
High Isolation	With reverse isolation of 37 dB (25 dB directivity), the AVA-24+ is an excellent choice for buffering broadband circuits. It is an ideal LO driver amplifier and provides designers system flexibility and margin when integrating cascaded RF components.
Manufacturability	MSL1 and ESD Class1A (HBM) ratings minimize special handling on production lines.

Kev Features



For detailed performance speca

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IF/RF MICROWAVE COMPONENTS

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Wideband, Microwave **Monolithic Amplifier**

5-20 GHz

Product Features

- Gain, 12.3 dB typ. & Flatness, ±0.8 dB
- Output Power, up to +18.3 dBm typ.
- Excellent isolation, 37 dB typ.
- Single Positive Supply Voltage, 5V
- Integrated DC blocks, Bias-Tee & Microwave bypass capacitor
- Unconditionally Stable
- Aqueous washable; 3mm x 3mm SMT package

Typical Applications

- Military EW and Radar
- DBS
- Wideband Isolation amplifier
- Microwave point-to-point radios
- Satellite systems



CASE STYLE: DQ849 PRICE: \$19.95 ea. QTY. (1-9)

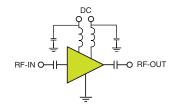
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

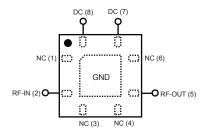
The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

AVA-24+ is a wideband medium power monolithic amplifier with outstanding gain flatness up to 20 GHz. It is manufactured using PHEMT* technology and is unconditionally stable. Its outstanding isolation enables it to be used as a wideband isolation amplifier or buffer amplifier in a variety of microwave systems.

simplified schematic and pad description





Function	Pad Number	Description (See Application Circuit, Fig. 2)
RF-IN	2	RF input pad
RF-OUT	5	RF output pad
DC	7(V _{D1}),8 (V _{D2})	DC power supply (short pins 7&8 externally)
GND	paddle in center of bottom	Connected to ground
NOT USED	1,3,4,6	No internal connection; recommended use: per PCB Layout PL-328
ADagudamambia Llinh Fla		No internal connection, recommended use. per FOB Layout FL-526

*Pseudomorphic High Electron Mobility Transistor.

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For detailed performance spec:

REV. OF M126227 AVA-24+

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Wideband Monolithic PHEMT MMIC Amplifier



Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range		5.0		20.0	GHz
DC Voltage (VD1, VD2)			5.0		V
DC Current (I _{D1} +I _{D2})			134	145	mA
	5.0	1	12.4		
	8.0	10.0	12.7		
	10.0	10.0	12.4		
Q-in	12.0		12.0		-10
Gain	14.0		11.7		dB
	16.0		12.6		
	18.0	10.0	12.6		
	20.0	9.0	11.5		
	5.0		12.7		
	8.0	10.0	25.7		
	10.0	10.0	17.9		
Input Poturn Loco	12.0		12.4		dB
Input Return Loss	14.0		11.3		UD
	16.0	10.0	15.8		
	18.0		11.7		
	20.0		16.9		
	5.0		30.0		
	8.0	10.0	25.0		
	10.0	10.0	18.6		
Output Return Loss	12.0		14.3		dB
Output Heldin Loss	14.0		13.6		uD
	16.0	10.0	20.3		
	18.0		19.0		
	20.0		11.5		
	5.0		26.2		
	8.0		26.3		
	10.0		26.5		
Output IP3	12.0		26.3		dBm
	14.0		26.0		
	16.0		25.4		
	18.0		24.5		
	20.0		23.8		
	5.0		18.8		
	8.0		18.7		
	10.0	16.0	18.6		
Output Power @ 1 dB compression	12.0		18.7		dBm
	14.0		18.5		
	16.0		18.0		
	18.0		17.4		
	20.0		18.6		
	5.0		7.0		
	8.0		6.3 5.6		
Noise Figure	10.0		5.6		
Noise Figure	12.0		6.5		dB
	14.0		6.5		
	16.0		6.1		
	18.0		6.1		
	20.0		6.7		
Directivity (Isolation-Gain)			25.0		dB
DC Current Variation vs. Temperature ⁽²⁾			-0.087		mA/°C
Thermal Resistance			47		°C/W

Electrical Specifications⁽¹⁾ at 25°C, Zo=50Ω, (refer to characterization circuit, Fig. 1)

Absolute Maximum Ratings⁽³⁾

Parameter	Ratings
Operating Temperature (4)	-40°C to 85°C
Storage Temperature	-55°C to 100°C
Channel Temperature	160°C
DC Voltage (Pad 7,8)	5.5V
Voltage (Pads 2, 5)	10V
Power Dissipation	860 mW
DC Current (Pad 7+8)	160mA
Input Power	20

(1) Measured on Mini-Circuits Characterization test fixture TB-547-1+ See Characterization Test Circuit (Fig. 1)

- ⁽²⁾ (Current at 85°C Current at -45°C)/130
 ⁽³⁾ Permanent damage may occur if any of these limits are exceeded.
- These maximum ratings are not intended for continuous normal operation. ⁽⁴⁾ Defined with reference to ground pad temperature.

 Input Power
 For detailed performance specs

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Characterization Test Circuit

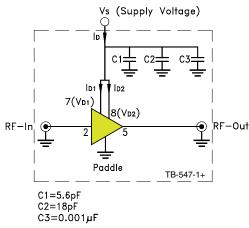
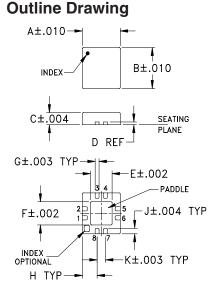


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-547-1+) Gain, Output power at 1dB compression (P1dB), Noise Figure, Output IP3 (OIP3) are measured using Agilent's N5242A PNA-X microwave network analyzer.

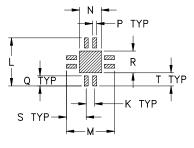
Conditions:

1. Gain: Pin=-25 dBm

2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, -10 dBm/tone at output. 3. Vs adjusted for 5V at device (V_{D1} and V_{D2}), compensating loss of bias lines.



PCB Land Pattern



Suggested Layout, Tolerance to be within $\pm .002$

Outline Dimensions (inch)

Α	В	С	D	E	F	G	н	J	
.118	.118	.035	.008	.067	.067	.012	.046	.016	
3.00	3.00	0.89	0.20	1.70	1.70	0.30	1.17	0.41	
K	L	M	N	Р	Q	R	S	Т	wt
	L .148								
.026		.148	.067	.012	.031	.067	.061	.041	grams

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Recommended Application Circuit

(refer to evaluation board for PCB Layout and component values)

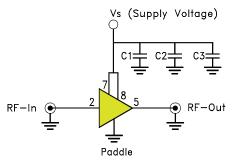


Fig 2. Recommended Application Circuit



Product Marking



black body

model family designation

Additional Detailed Technical Information

Additional information is available on our web site www.minicircuits.com. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: DQ849 Plastic package, exposed paddle, lead finish: tin silver nickel

Tape & Reel: F104

Suggested Layout for PCB Design: PL-328

Evaluation Board: TB-547-1+

Environmental Ratings: ENV08T1

ESD Rating

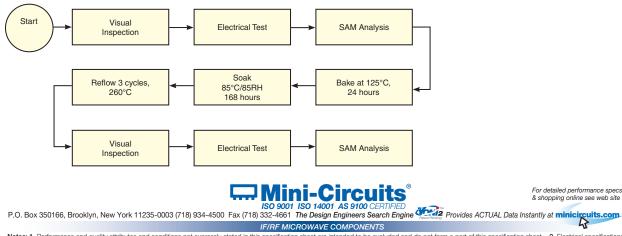
Human Body Model (HBM): 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): M1 (passes 25V) in accordance with ANSI/ESD STM5.2-1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D





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